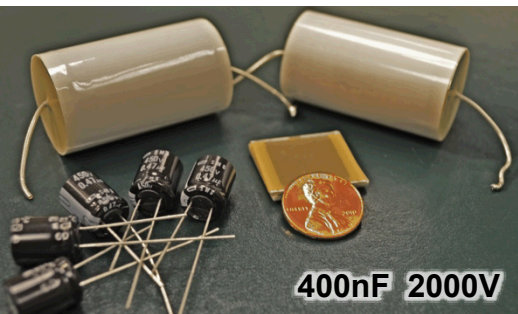
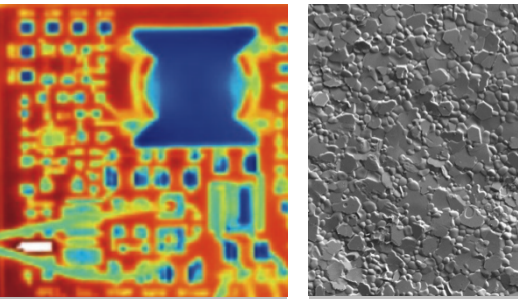


Processing of $\text{Bi}(\text{Zn}_{1/2}\text{Ti}_{1/2})\text{O}_3$ - BaTiO_3 dielectrics for reliable high field operation

or: what you don't know can't hurt you... can it?



Geoff Brennecka, Harlan Brown-Shaklee and Mia Blea
Sandia National Laboratories

Natthaphon Raengethon and David Cann
Oregon State University



*Exceptional
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interest*



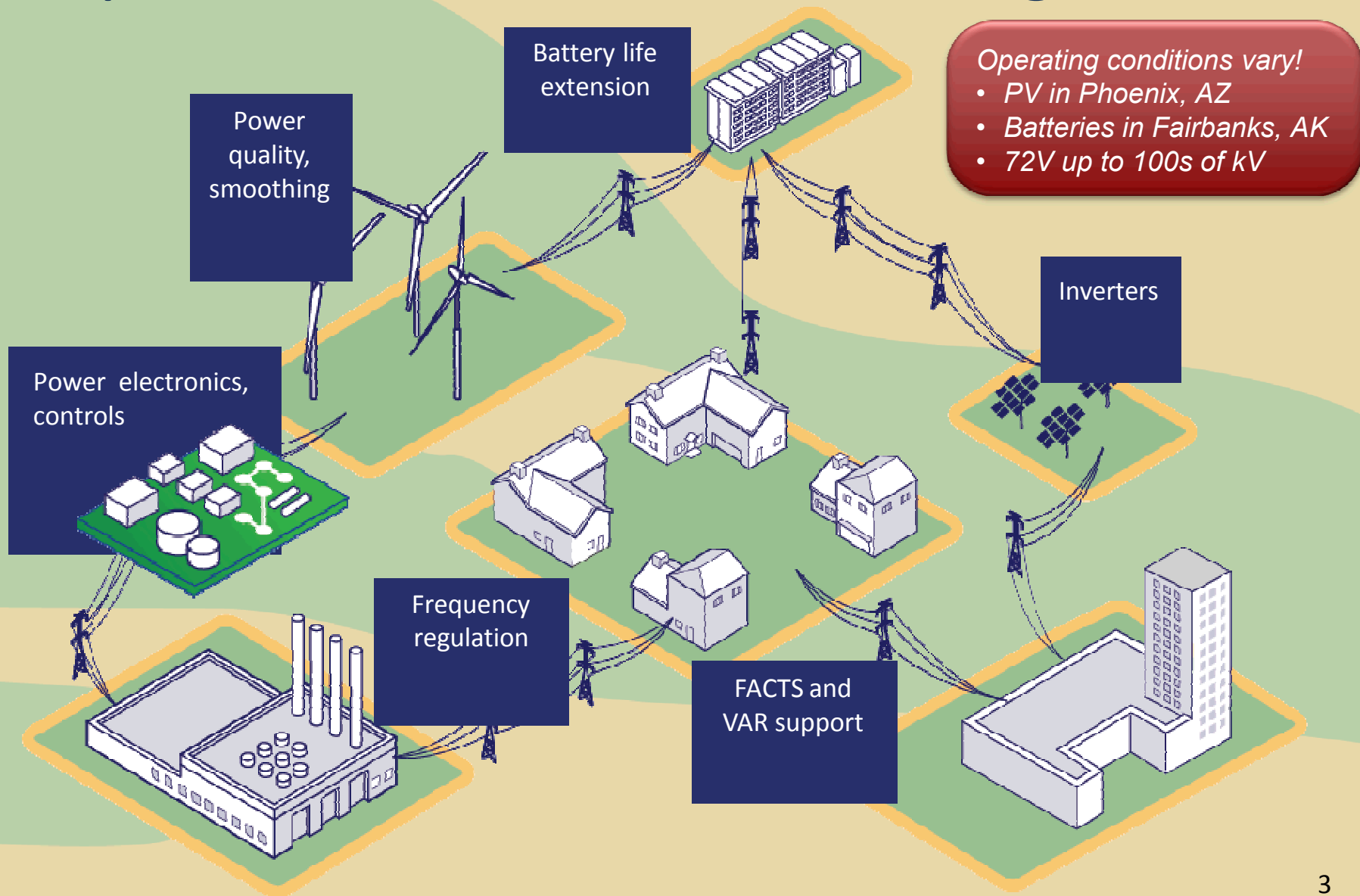
Sandia National Laboratories is a multi-program laboratory managed and operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin Corporation, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000.

Acknowledgements

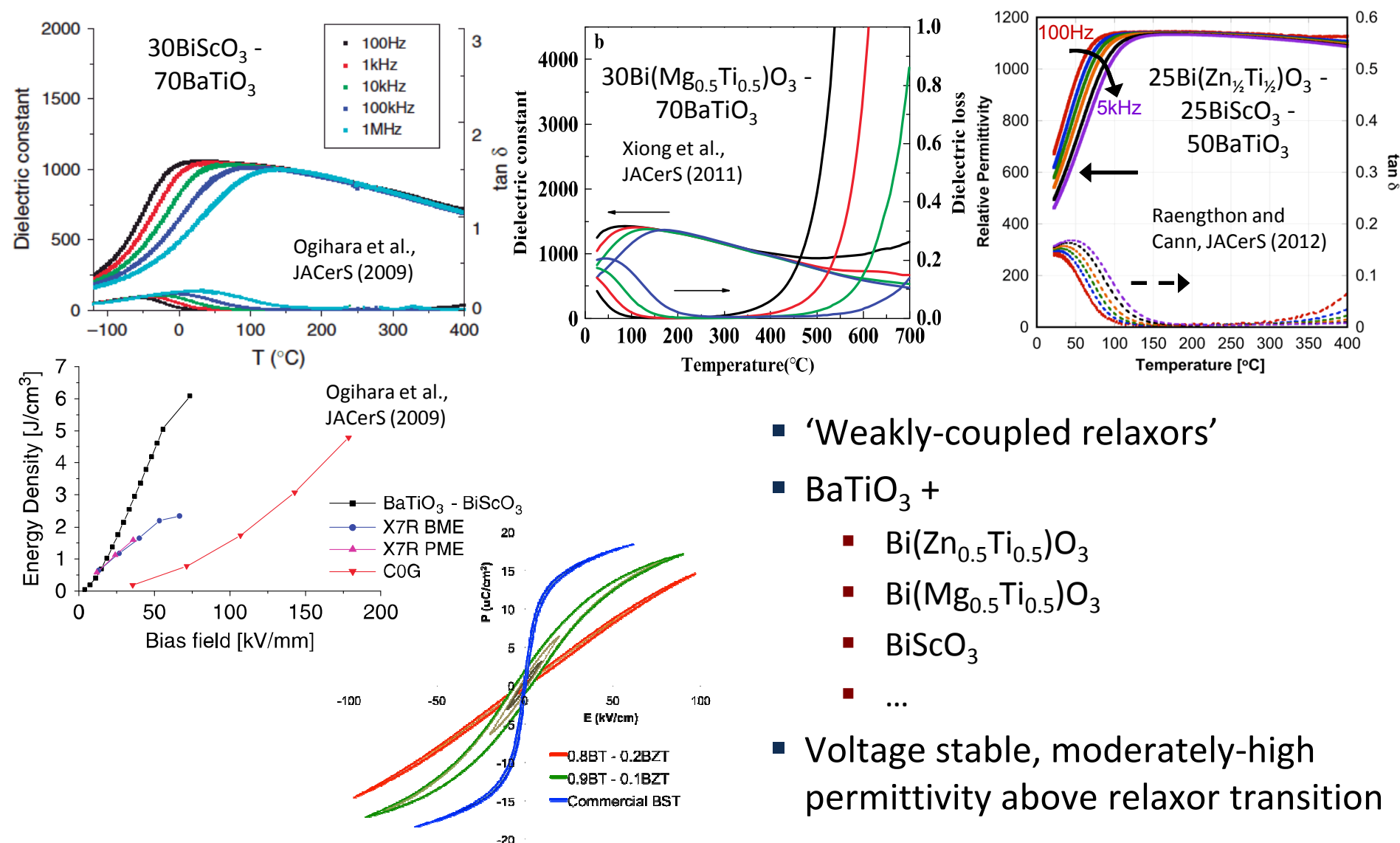
- This work would not have been possible without:
 - Alice Kilgo
 - Bonnie McKenzie
 - Joe Michael
 - Ping Lu
 - Kevin Ring (NM Tech)
 - Yu Hong Jeon (OSU)
 - Adrian Casias
 - Adrian Wagner
 - Mark Rodriguez
 - John Borchardt
 - Greg Lyons
 - Jim Klarkowski



Capacitor Needs for Grid Storage



Bi-modified BaTiO₃ Relaxors



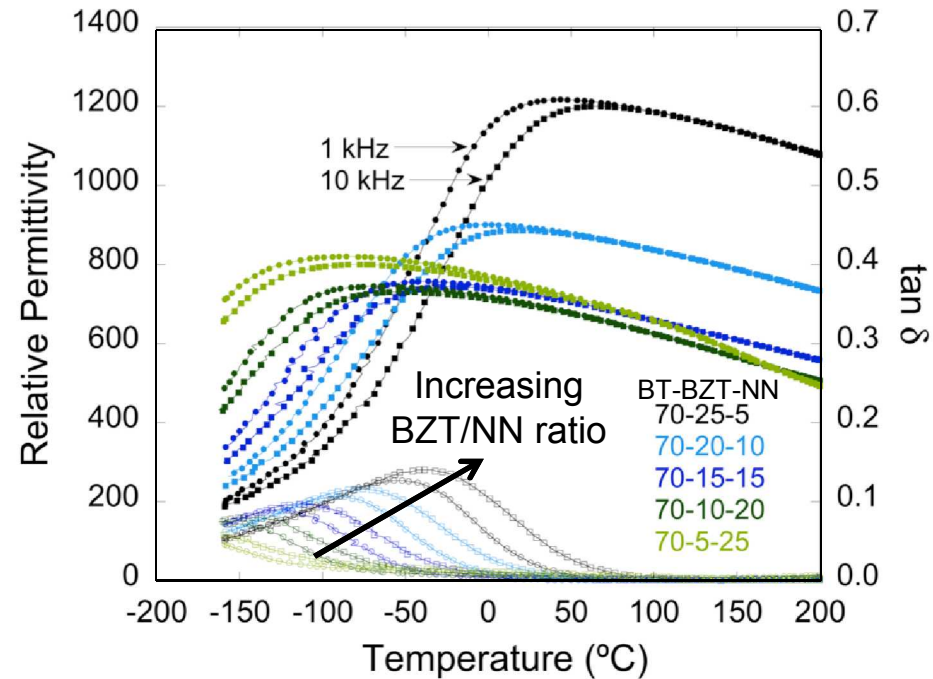
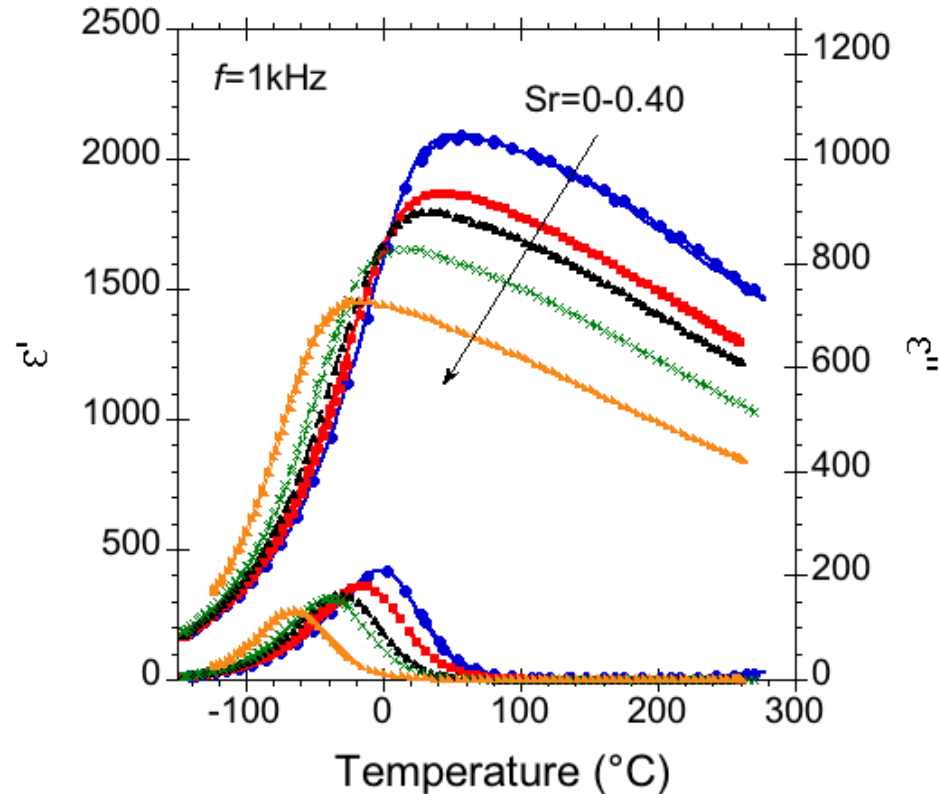
■ 'Weakly-coupled relaxors'

■ BaTiO₃ +

- Bi(Zn_{0.5}Ti_{0.5})O₃
- Bi(Mg_{0.5}Ti_{0.5})O₃
- BiScO₃
- ...

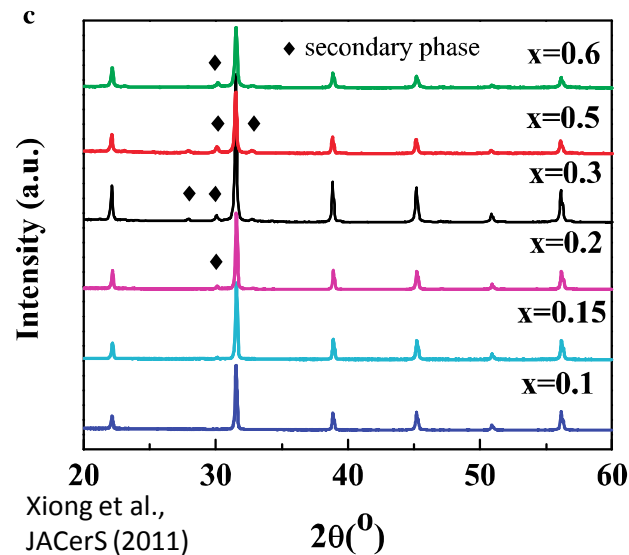
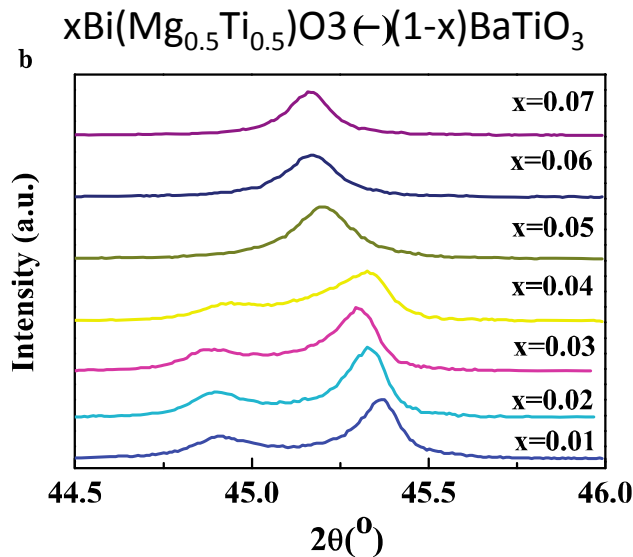
■ Voltage stable, moderately-high permittivity above relaxor transition

BT-BZT: Modifications can Shift T_{\max}

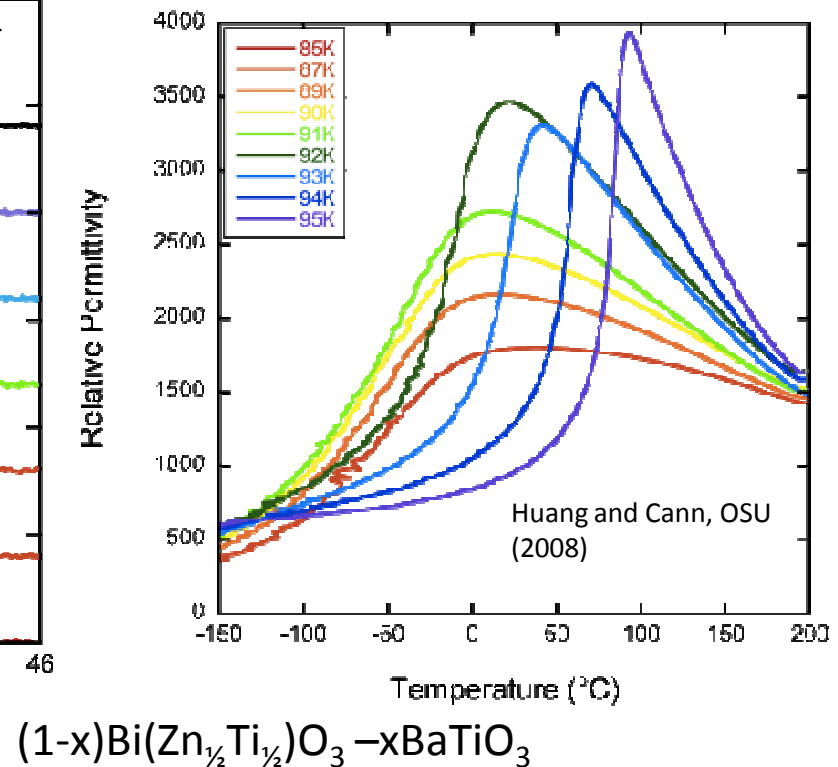
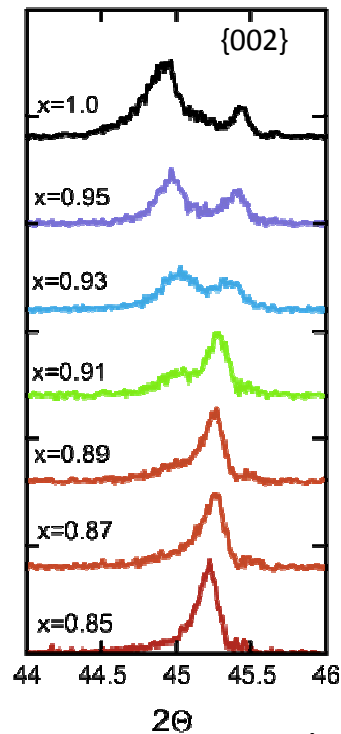


- NaNbO_3 , SrTiO_3 , BaZrO_3 , La_{Bi}^x , etc. shift T_{\max} down
- BiScO_3 , PbTiO_3 and others shift T_{\max} up

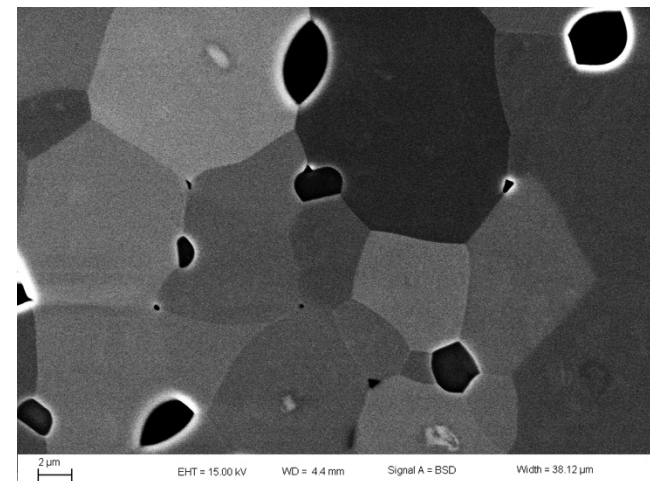
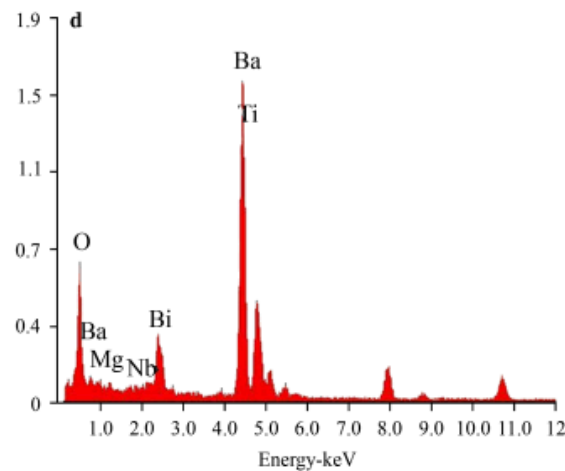
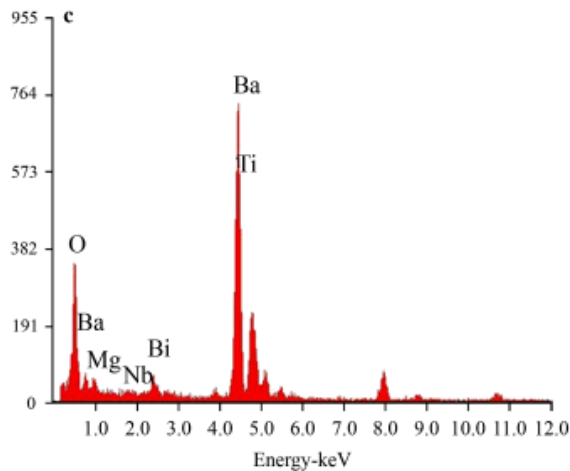
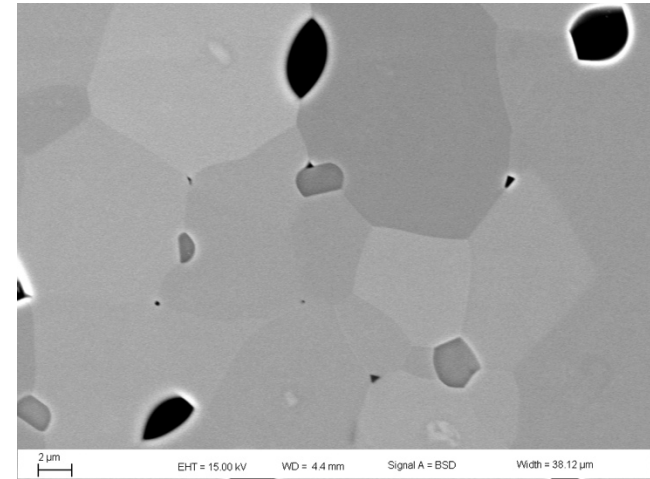
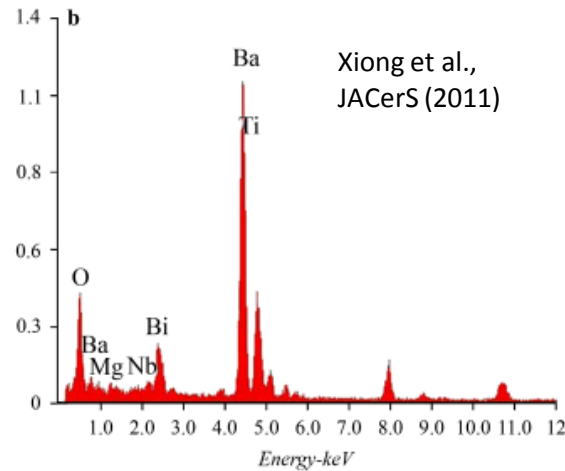
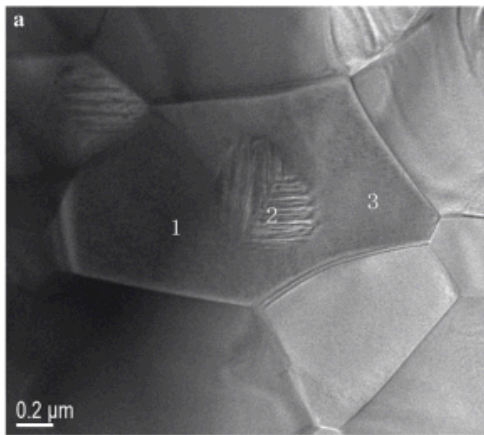
Diffraction Studies are Limited



- Pure $\text{Bi}(\text{Zn}_{0.5}\text{Ti}_{0.5})\text{O}_3$ and $\text{Bi}(\text{Mg}_{0.5}\text{Ti}_{0.5})\text{O}_3$ end members unstable; additional phases observed for large substitutions
- Unusual behaviors suggest complexity...



BT-BZT: Modifications can Shift T_{\max}



- Reminder: 'single phase by XRD' != homogeneous

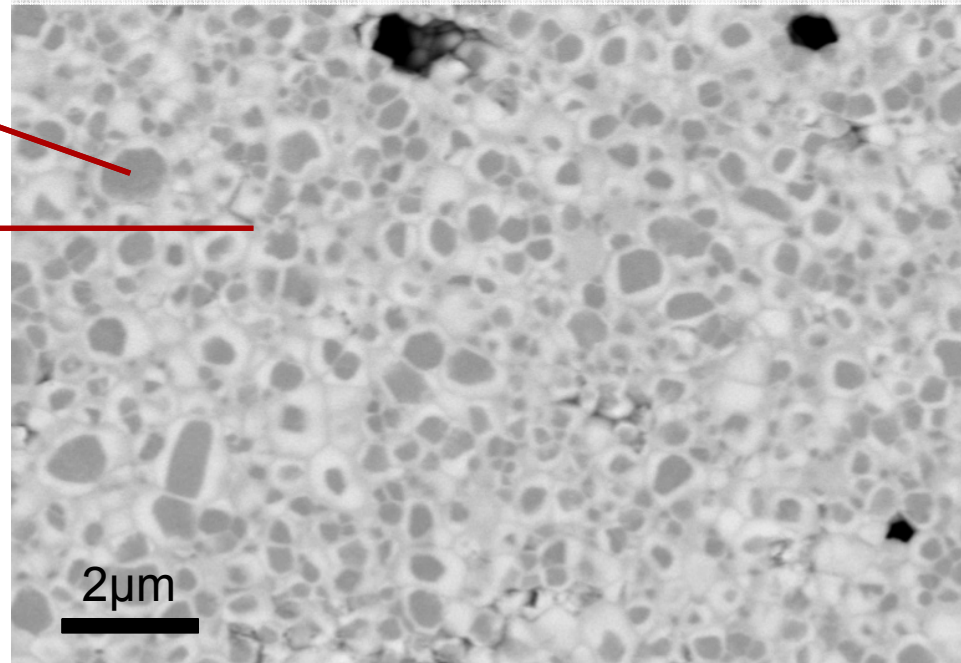
BT-BZT: Modifications can Shift T_{\max}

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1kHz



Intentionally fabricated BaTiO_3 core, Bi-rich shell

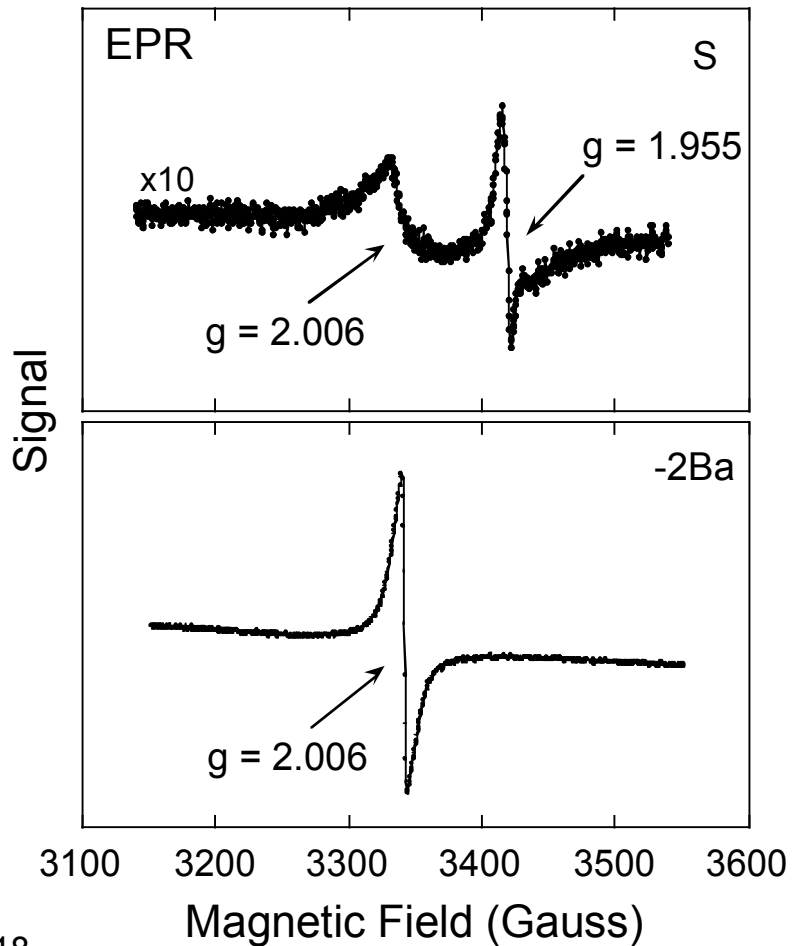
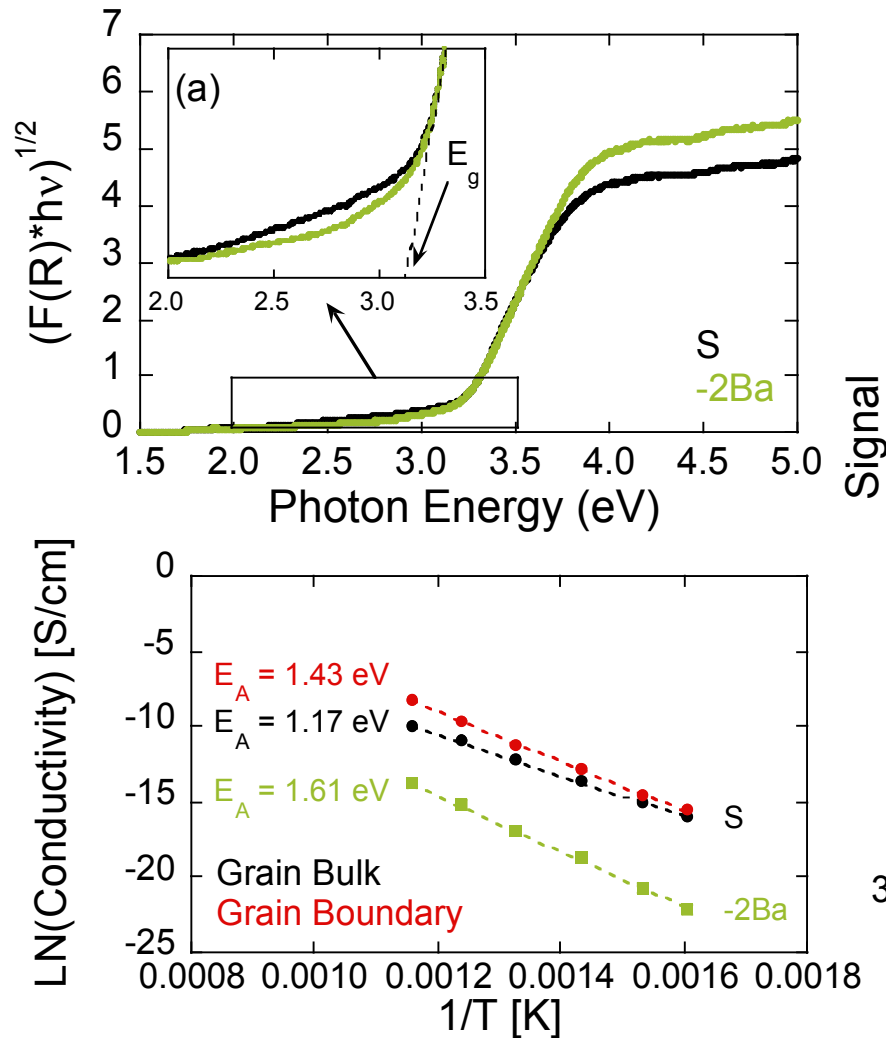


2μm

Core exhibits $T_C \sim 125^\circ\text{C}$
Shell exhibits relaxor behavior

- Reminder: 'single phase by XRD' != homogeneous

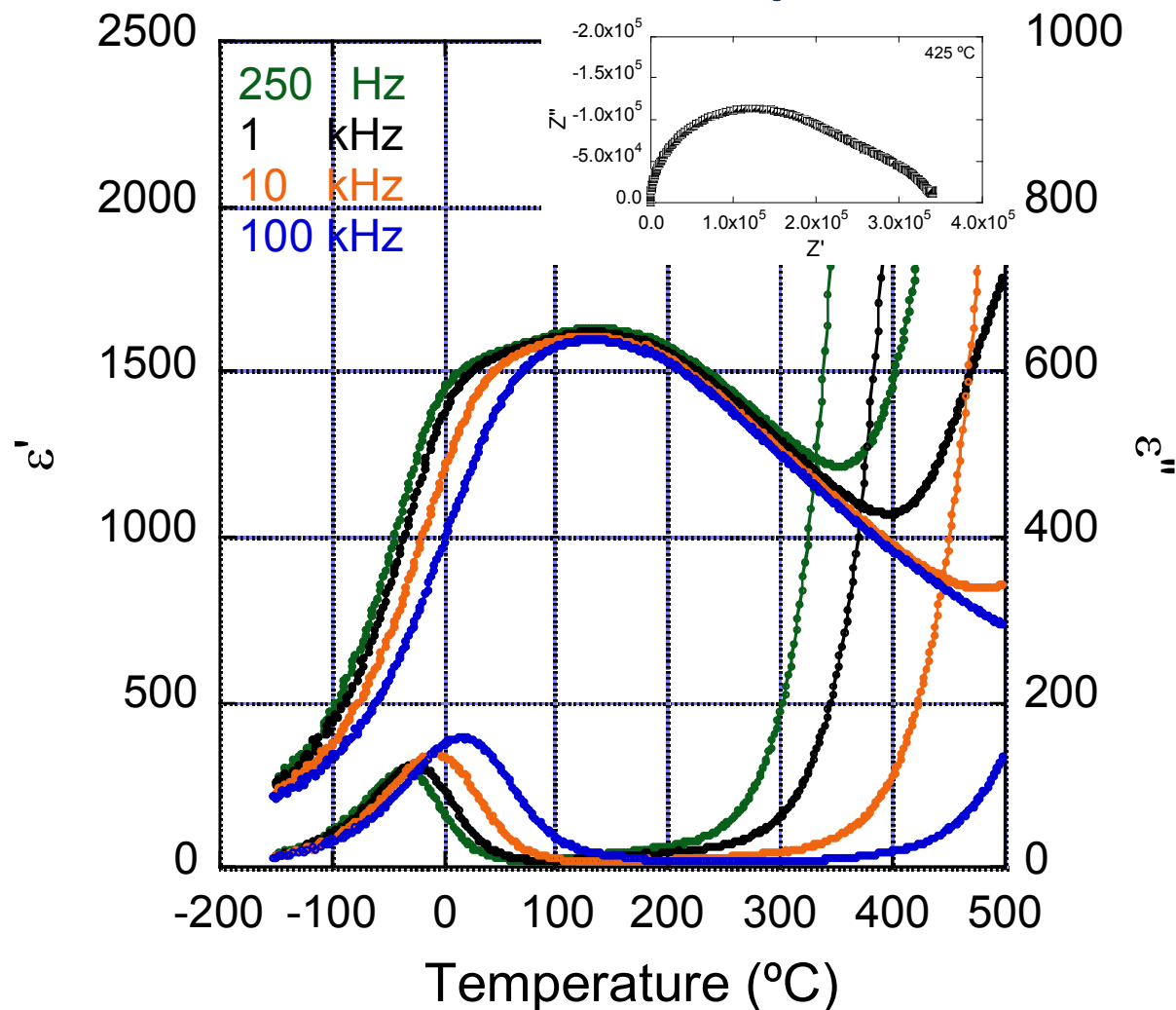
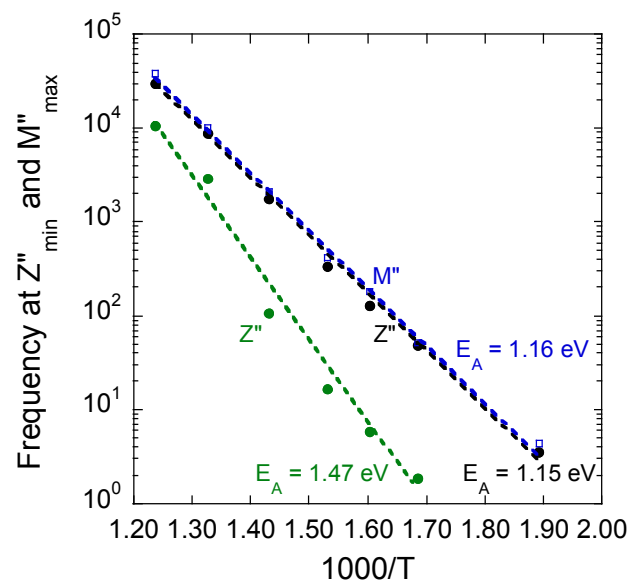
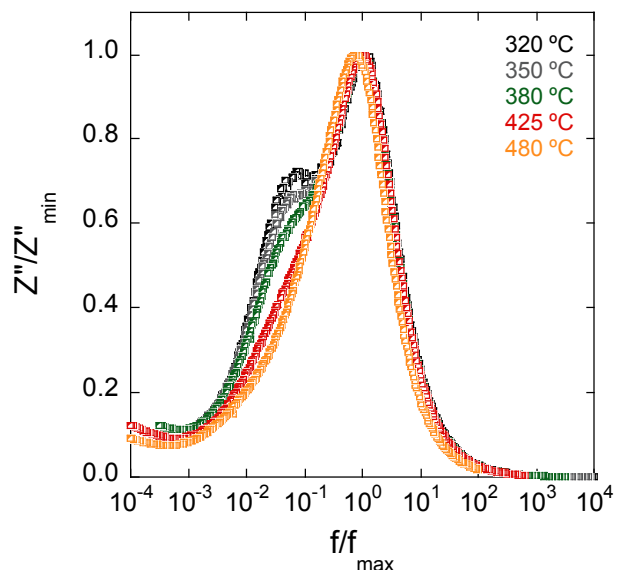
Defects: Optical & Electrical Info



Raengthon, et al., Appl. Phys. Lett. (2012)

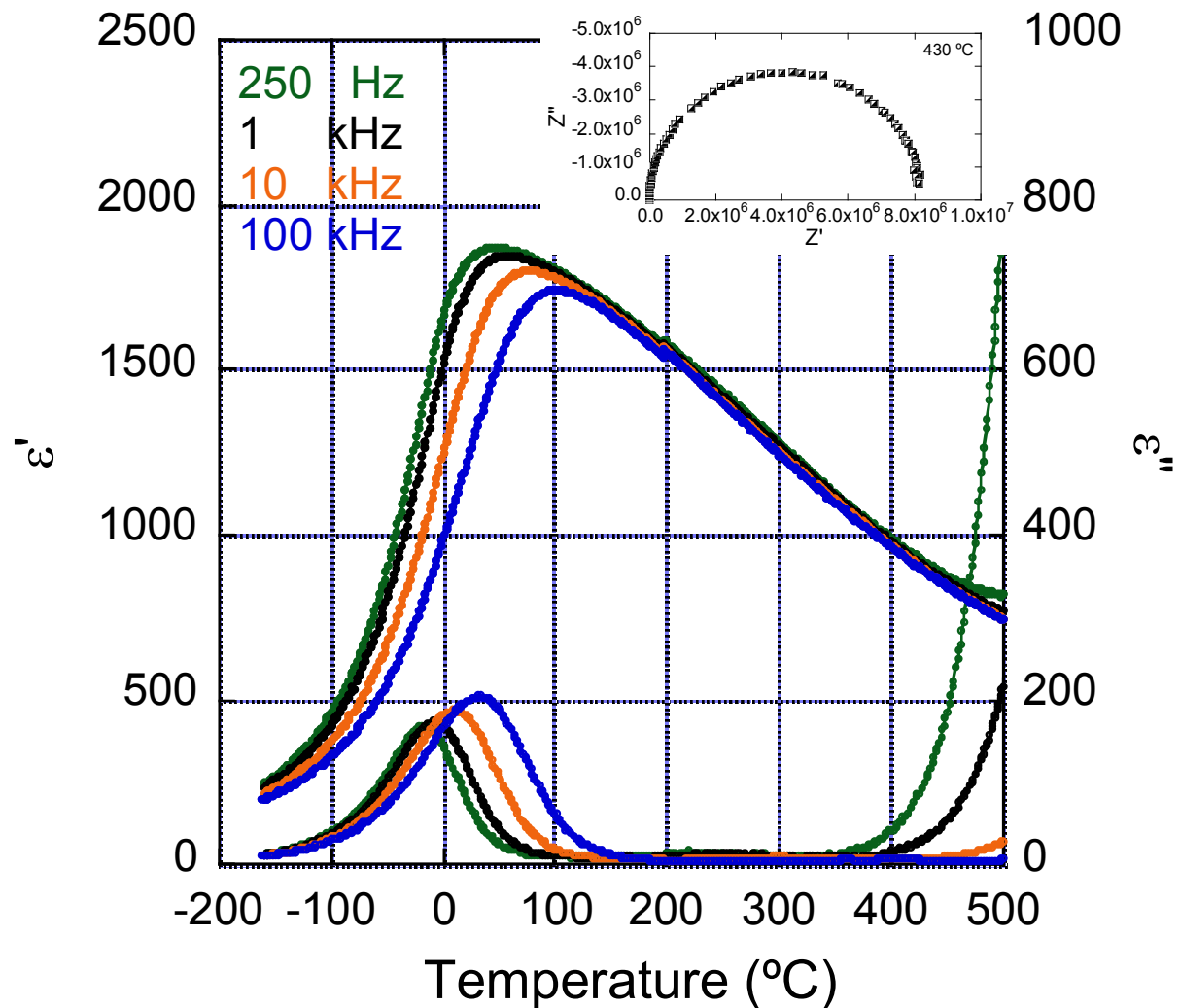
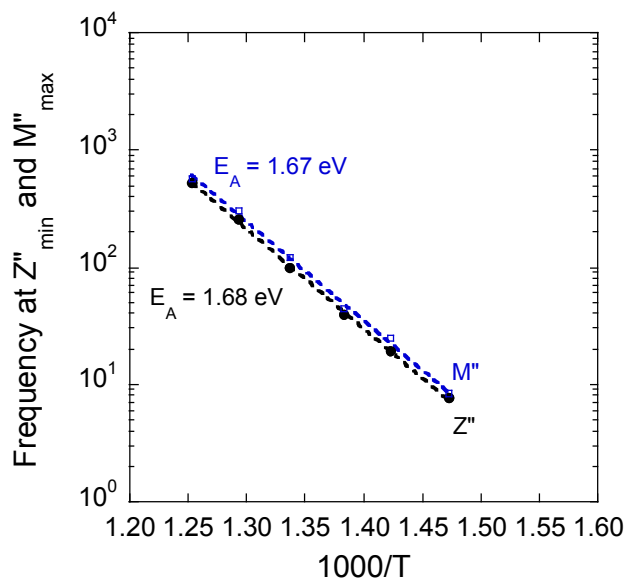
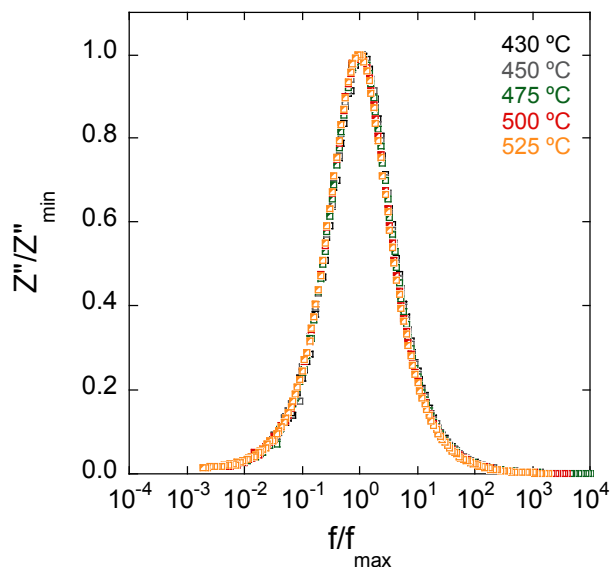
- Defect studies suggest $V_{Ba}'' - V_O^{\bullet\bullet}$ pairs are strong carrier traps

Nominally Stoichiometric, Acceptor



- (Nominally) stoichiometric and acceptor-doped samples are 'electrically heterogeneous'

Donor-Doped



- Donor-doped samples are 'electrically homogeneous'

Typical Microstructures

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90BT-10BZT, 1200C

Typical Microstructures

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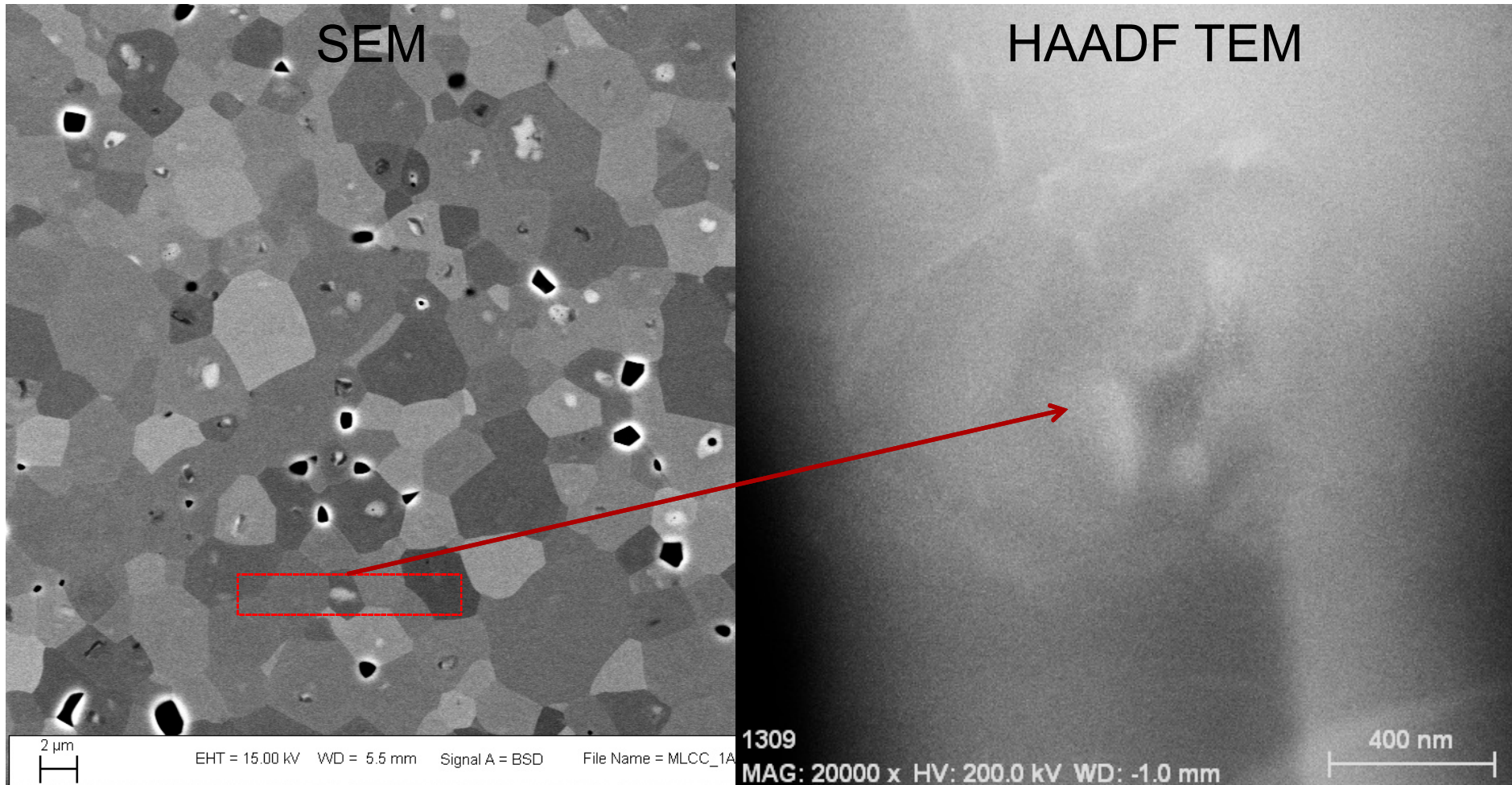
80BT-20BZT, 1200C

Typical Microstructures

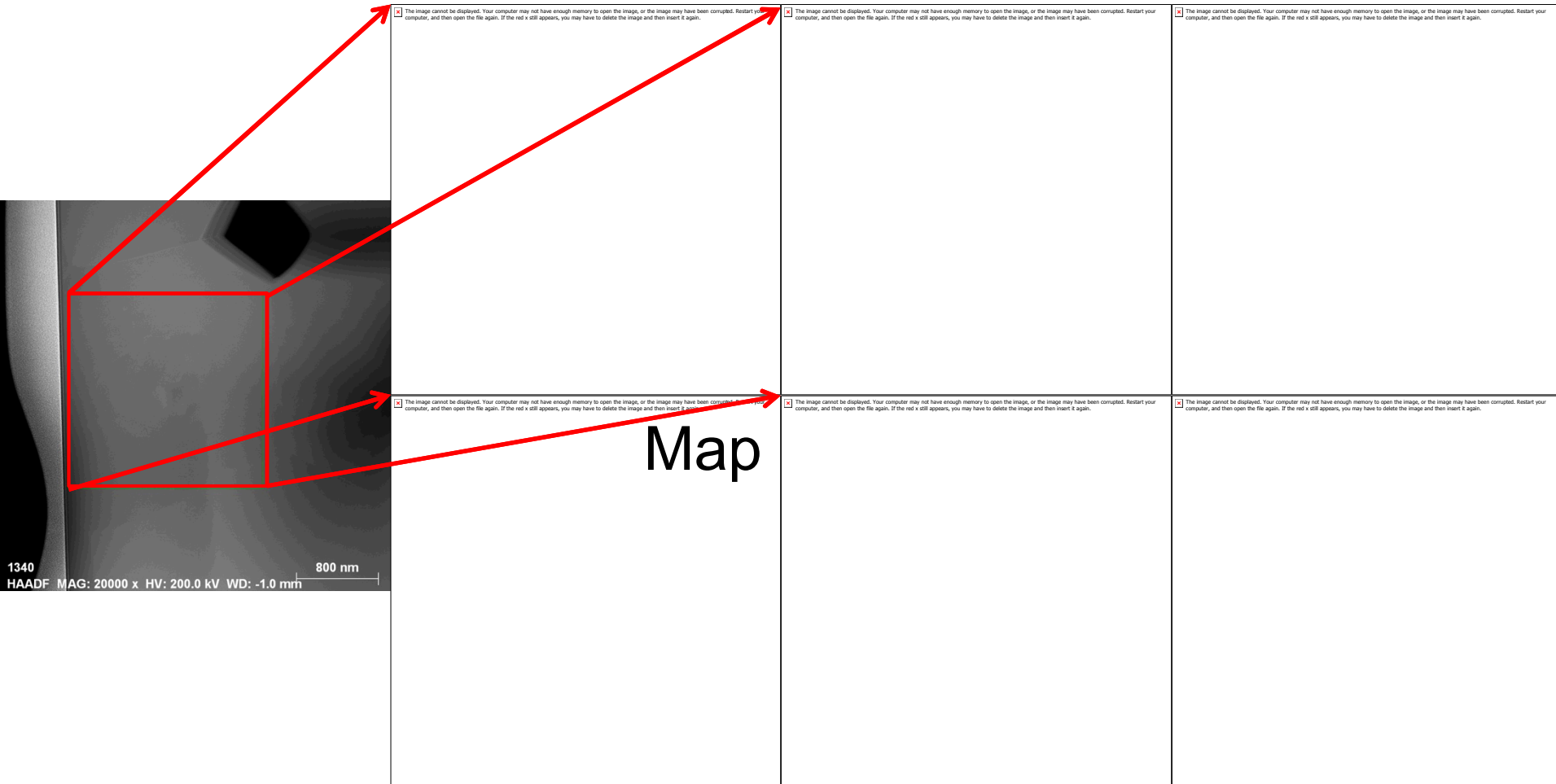
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80BT-20BZT, 1200C

Compositional Variation



Bi and Zn Variation



Summary

- Electrical response(s) of weakly-coupled relaxor systems tied to multi-scale chemical heterogeneities
- Complex microscale chemical distributions appear to be (somewhat) independent of relaxor behavior, but likely contribute strongly to high-field electrical behavior
- Reminder: no single view (or characterization technique) provides the complete picture!